

#### **FEATURES**

- Member of the Texas Instruments Widebus™
   Family
- EPIC<sup>™</sup> (Enhanced-Performance Implanted CMOS) Submicron Process
- Output Ports Have Equivalent 26-Ω Series Resistors, So No External Resistors Are Required
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages

NOTE: For tape-and-reel order entry, the DGGR package is abbreviated to GR.

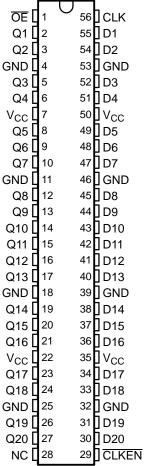
#### DESCRIPTION

This 20-bit flip-flop is designed for low-voltage 1.65-V to 3.6-V  $V_{\rm CC}$  operation.

The 20 flip-flops of the SN74ALVCH162721 are edge-triggered D-type flip-flops with qualified clock storage. On the positive transition of the clock (CLK) input, the device provides true data at the Q outputs if the clock-enable (CLKEN) input is low. If CLKEN is high, no data is stored.

A buffered output-enable ( $\overline{OE}$ ) input places the 20 outputs in either a normal logic state (high or low level) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance

# DGG OR DL PACKAGE (TOP VIEW)



NC - No internal connection

state and increased drive provide the capability to drive bus lines without interface or pullup components.  $\overline{\text{OE}}$  does not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The outputs, which are designed to sink up to 12 mA, include equivalent 26- $\Omega$  resistors to reduce overshoot and undershoot.

The SN74ALVCH162721 is characterized for operation from -40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

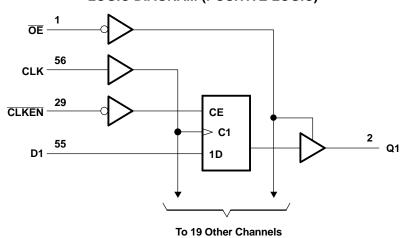
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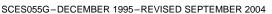


# FUNCTION TABLE (each flip-flop)

	INP	UTS		OUTPUT			
ŌĒ	CLKEN	CLKEN CLK D					
L	Н	X	Χ	$Q_0$			
L	L	1	Н	Н			
L	L	$\uparrow$	L	L			
L	L	L or H	Χ	$Q_0$			
Н	X	X	Χ	Z			

# LOGIC DIAGRAM (POSITIVE LOGIC)







# ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			М	IN	MAX	UNIT
$V_{CC}$	Supply voltage range		-(	).5	4.6	V
VI	Input voltage range <sup>(2)</sup>				4.6	V
Vo	Output voltage range <sup>(2)(3)</sup>		-(	).5 V	/ <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0			-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0			-50	mA
Io	Continuous output current				±50	mA
	Continuous current through each V <sub>CC</sub> or GND				±100	mA
0	Dealer at the second increased (4)	DGG package			81	°C/W
$\theta_{JA}$	Package thermal impedance (4)	DL package			74	°C/W
T <sub>stg</sub>	Storage temperature range		-	65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# **RECOMMENDED OPERATING CONDITIONS**(1)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage		1.65	3.6	V
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>		
$V_{IH}$	High-level input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	1.7		V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2		
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.0	$35 \times V_{CC}$	
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V		0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V		0.8	
$V_{I}$	Input voltage	·	0	V <sub>CC</sub>	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.65 V		-2	
	Libely level autout august	V <sub>CC</sub> = 2.3 V		-6	A
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 2.7 V		-8	mA
		V <sub>CC</sub> = 3 V		-12	
		V <sub>CC</sub> = 1.65 V		2	
	Law lawal autout aumant	V <sub>CC</sub> = 2.3 V		6	A
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 2.7 V		8	mA
		V <sub>CC</sub> = 3 V		12	
Δt/Δν	Input transition rise or fall rate			10	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> This value is limited to 4.6 V, maximum.

<sup>(4)</sup> The package thermal impedance is calculated in accordance with JESD 51.



### **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TES	T CONDITIONS	V <sub>cc</sub>	MIN	TYP <sup>(1)</sup>	MAX	UNIT
	I <sub>OH</sub> = -100 μA		1.65 V to 3.6 V	V <sub>CC</sub> - 0.2			
	$I_{OH} = -2 \text{ mA}$		1.65 V	1.2			
	$I_{OH} = -4 \text{ mA}$		2.3 V	1.9			
V <sub>OH</sub>	I 6 m A		2.3 V	1.7			V
	$I_{OH} = -6 \text{ mA}$		3 V	2.4			
	I <sub>OH</sub> = -8 mA		2.7 V	2			
	I <sub>OH</sub> = -12 mA		3 V	2			
	$I_{OL} = 100  \mu A$		1.65 V to 3.6 V			0.2	
	I <sub>OL</sub> = 2 mA		1.65 V			0.45	
	I <sub>OL</sub> = 4 mA		2.3 V			0.4	
V <sub>OL</sub>	I 6 m A		2.3 V			0.55	V
	$I_{OL} = 6 \text{ mA}$		3 V			0.55	
	I <sub>OL</sub> = 8 mA		2.7 V			0.6	
	I <sub>OL</sub> = 12 mA		3 V			8.0	
I <sub>I</sub>	$V_I = V_{CC}$ or GND		3.6 V			±5	μΑ
	V <sub>I</sub> = 0.58 V		1.65 V	25			
	V <sub>I</sub> = 1.07 V		1.65 V	-25			
	V <sub>I</sub> = 0.7 V		2.3 V	45			
I <sub>I(hold)</sub>	V <sub>I</sub> = 1.7 V		2.3 V	-45			μΑ
	V <sub>I</sub> = 0.8 V		3 V	75			
	V <sub>I</sub> = 2 V		3 V	-75			
	$V_I = 0$ to 3.6 $V^{(2)}$		3.6 V			±500	
I <sub>OZ</sub>	$V_O = V_{CC}$ or GND		3.6 V			±10	μА
I <sub>CC</sub>	$V_I = V_{CC}$ or GND,	I <sub>O</sub> = 0	3.6 V			40	μΑ
$\Delta I_{CC}$	One input at V <sub>CC</sub> - 0.6 V,	Other inputs at V <sub>CC</sub> or GND	3 V to 3.6 V			750	μΑ
C <sub>i</sub>	$V_I = V_{CC}$ or GND		3.3 V		3.5		pF
C <sub>o</sub>	$V_O = V_{CC}$ or GND		3.3 V		7		pF

### **TIMING REQUIREMENTS**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1 through Figure 3)

			V <sub>CC</sub> =	1.8 V	V <sub>CC</sub> = ± 0.	2.5 V 2 V	V <sub>CC</sub> =	2.7 V	V <sub>CC</sub> = ± 0.	3.3 V 3 V	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>clock</sub>	Clock frequency			(1)		150		150		150	MHz
t <sub>w</sub>	Pulse duration, CLK high or low		(1)		3.3		3.3		3.3		ns
+	Sotup time	Data before CLK↑	(1)		4		3.6		3.1		no
t <sub>su</sub>	Setup time	CLKEN before CLK↑	(1)		3.4		3.1		2.7		ns
	I lold time	Data after CLK↑	(1)		0		0		0		
t <sub>h</sub>	Hold time	CLKEN after CLK↑	(1)		0		0		0		ns

<sup>(1)</sup> This information was not available at the time of publication.

All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ . This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.



### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1 through Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1	1.8 V	V <sub>CC</sub> = 2 ± 0.2	2.5 V ? V	V <sub>CC</sub> = 2	2.7 V	V <sub>CC</sub> = 3 ± 0.3	3.3 V V	UNIT
	(INPOT)	(001F01)	MIN	TYP	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>max</sub>			(1)		150		150		150		MHz
t <sub>pd</sub>	CLK	Q		(1)	1	6.7		6.2	1	5.3	ns
t <sub>en</sub>	ŌĒ	Q		(1)	1	7.2		7	1	5.8	ns
t <sub>dis</sub>	ŌĒ	Q		(1)	1	6.3		5.4	1	5	ns

<sup>(1)</sup> This information was not available at the time of publication.

# **OPERATING CHARACTERISTICS**

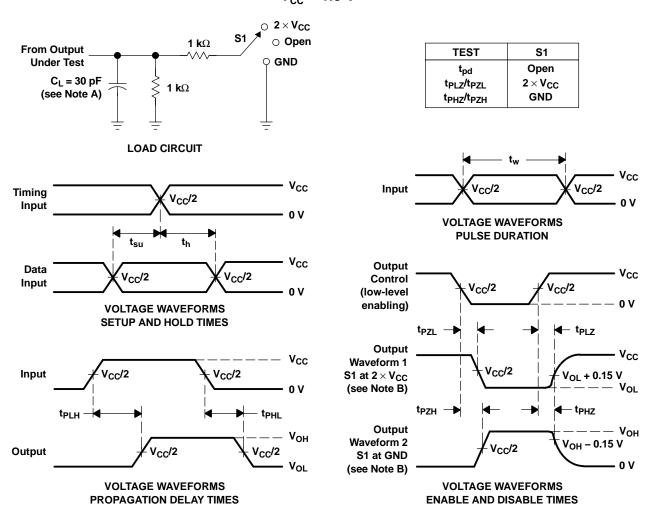
 $T_A = 25^{\circ}C$ 

	PARAMETER	!	TEST C	ONDITIONS	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	UNIT
C	Power dissipation	Outputs enabled	$C_1 = 50 \text{ pF}.$	f = 10 MHz	(1)	55	59	pF
$C_{pd}$	capacitance	Outputs disabled	$C_L = 50 \text{ pr},$	I = IU WINZ	(1)	46	49	ρr 

<sup>(1)</sup> This information was not available at the time of publication.



# PARAMETER MEASUREMENT INFORMATION $V_{cc} = 1.8 \text{ V}$



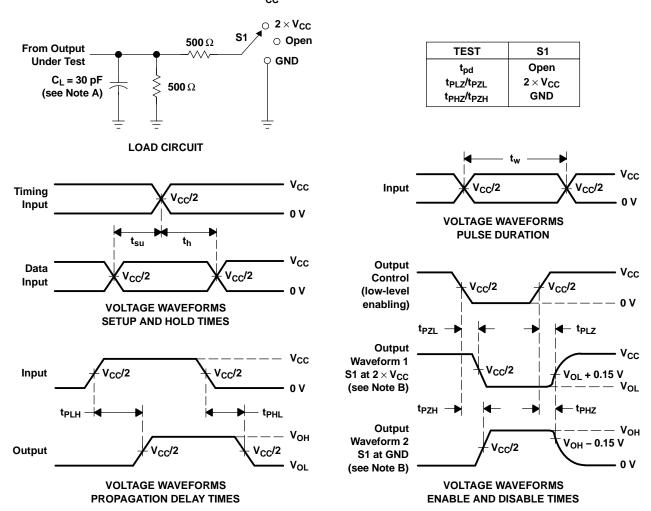
NOTES: A. C<sub>1</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z  $_{O}$  = 50  $\Omega$ ,  $t_{f}$   $\leq$  2 ns,  $t_{f}$   $\leq$  2 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PL7</sub> and t<sub>PH7</sub> are the same as t<sub>dis</sub>.
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 1. Load Circuit and Voltage Waveforms



# PARAMETER MEASUREMENT INFORMATION $V_{\rm CC}$ = 2.5 V $\pm$ 0.2 V



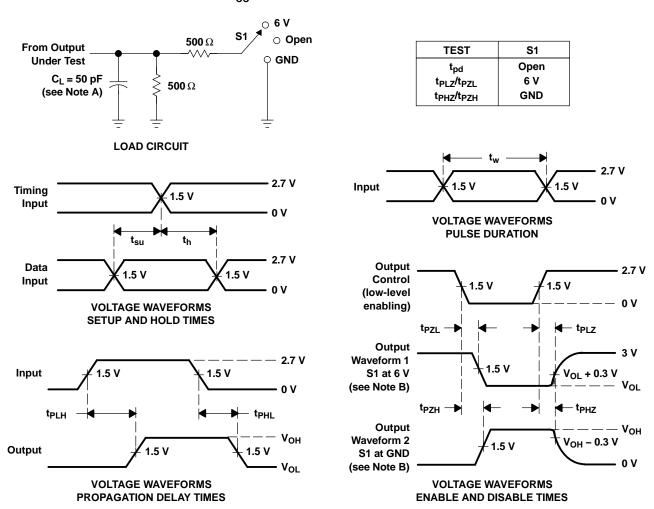
NOTES: A. C<sub>1</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50~\Omega$ ,  $t_f \leq$  2 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PL7</sub> and t<sub>PH7</sub> are the same as t<sub>dis</sub>.
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 2. Load Circuit and Voltage Waveforms



# PARAMETER MEASUREMENT INFORMATION $V_{CC}$ = 2.7 V AND 3.3 V $\pm$ 0.3 V



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \ \Omega$ ,  $t_f \leq$  2.5 ns.  $t_f \leq$  2.5 ns.
  - D. The outputs are measured one at a time with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 3. Load Circuit and Voltage Waveforms



# PACKAGE OPTION ADDENDUM

10-Dec-2020

#### PACKAGING INFORMATION

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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74ALVCH162721DLR	ACTIVE	SSOP	DL	56	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH162721	Samples
SN74ALVCH162721GR	ACTIVE	TSSOP	DGG	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH162721	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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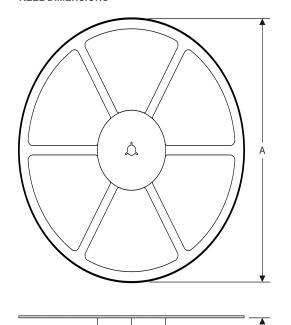
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# PACKAGE MATERIALS INFORMATION

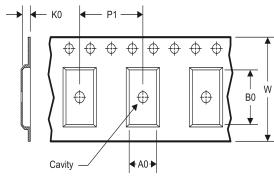
www.ti.com 14-Jul-2012

# TAPE AND REEL INFORMATION

### **REEL DIMENSIONS**







A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### TAPE AND REEL INFORMATION

### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALVCH162721DLR	SSOP	DL	56	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1
SN74ALVCH162721GR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1

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#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALVCH162721DLR	SSOP	DL	56	1000	367.0	367.0	55.0
SN74ALVCH162721GR	TSSOP	DGG	56	2000	367.0	367.0	45.0

# DL (R-PDSO-G56)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.





SMALL OUTLINE PACKAGE



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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